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Front Matter: Volume 7417

, "Front Matter: Volume 7417," Proc. SPIE 7417, Organic Field-Effect Transistors VIII, 741701 (17 September 2009); doi: 10.1117/12.846118

SPIE.

Event: SPIE Photonic Devices + Applications, 2009, San Diego, California, United States

PROCEEDINGS OF SPIE

Organic Field-Effect Transistors VIII

Zhenan Bao
Iain McCulloch
Editors

3–5 August 2009
San Diego, California, United States

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Volume 7417

Proceedings of SPIE, 0277-786X, v. 7417

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Author(s), "Title of Paper," in *Organic Field-Effect Transistors VIII*, edited by Zhenan Bao, Iain McCulloch, Proceedings of SPIE Vol. 7417 (SPIE, Bellingham, WA, 2009) Article CID Number.

ISSN 0277-786X

ISBN 9780819477071

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

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